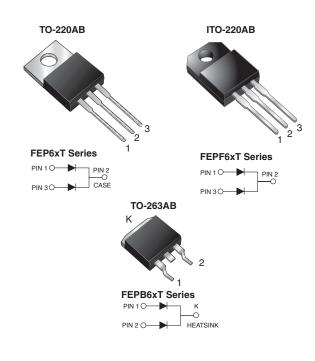


FEP(F,B)6AT thru FEP(F,B)6DT

Vishay General Semiconductor

Dual Common-Cathode Ultrafast Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	6.0 A				
V _{RRM}	50 V to 200 V				
I _{FSM}	75 A				
t _{rr}	35 ns				
V _F 0.975 V					
T _J max.	150 °C				

FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low leakage current
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, dc-to-dc converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	FEP6AT	FEP6BT	FEP6CT	FEP6DT	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V	
Maximum RMS voltage	V _{RMS}	35	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V	
Maximum average forward rectified current at T_C = 105 $^\circ C$	I _{F(AV)}	6.0				А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	75			A		
Operating storage and temperature range	T _J , T _{STG}	- 55 to + 150				°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		

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RoHS

COMPLIANT

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	FEP6AT	FEP6BT	FEP6CT	FEP6DT	UNIT
Maximum instantaneous forward voltage per diode $^{(1)}$	3.0 A		V _F	0.975			V	
Maximum DC reverse current at rated DC blocking voltage per diode		T _C = 25 °C T _C = 100 °C	I _R	5.0 50			μΑ	
Maximum reverse recovery time per diode	$I_{F} = 0.5 \text{ A}, I_{R} = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	35			ns	
Typical junction capacitance per diode	4.0 V, 1 M	Hz	CJ	28		pF		

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25 \degree C$ unless otherwise noted)							
PARAMETER	ETER SYMBOL FEP6 FEPF6 FEPB6 UNIT						
Typical thermal resistance from junction to case per diode	$R_{ ext{ heta}JC}$	3.6	5.1	3.6	°C/W		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	FEP6DT-E3/45	1.81	45	50/tube	Tube		
ITO-220AB	FEPF6DT-E3/45	1.97	45	50/tube	Tube		
TO-263AB	FEPB6DT-E3/45	1.33	45	50/tube	Tube		
TO-263AB	FEPB6DT-E3/81	1.33	81	800/reel	Tape and reel		
TO-220AB	FEP6DTHE3/45 (1)	1.81	45	50/tube	Tube		
ITO-220AB	FEPF6DTHE3/45 ⁽¹⁾	1.97	45	50/tube	Tube		
TO-263AB	FEPB6DTHE3/45 (1)	1.33	45	50/tube	Tube		
TO-263AB	FEPB6DTHE3/81 ⁽¹⁾	1.33	81	800/reel	Tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

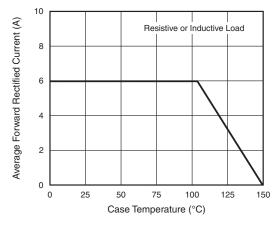


Figure 1. Maximum Forward Current Derating Curve

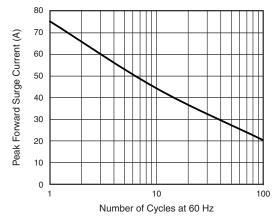


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

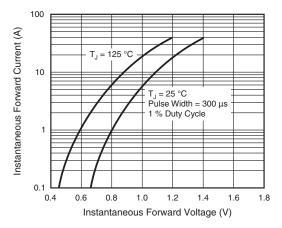


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

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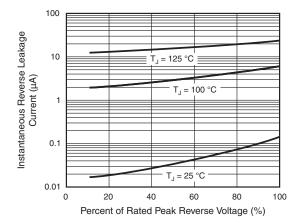


Figure 4. Typical Reverse Leakage Characteristics Per Diode

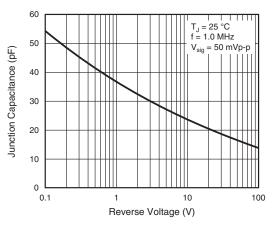


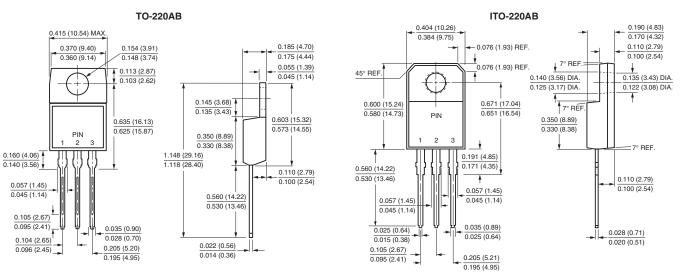
Figure 5. Typical Junction Capacitance Per Diode

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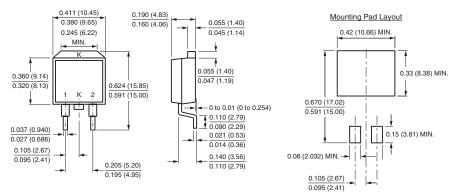
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB





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